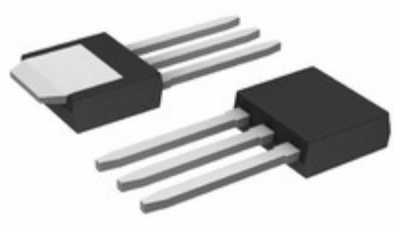






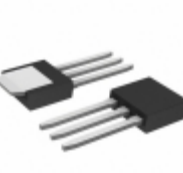


	<h2 style="color: red;">GP1M008A025PG</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">GP1M008A025PG</a>
	<b>Hersteller / Marke:</b>	<a href="#">Global Power Technologies Group</a>
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 250V 8A IPAK
<p style="font-size: small;">Image may be representation. See specs for product details.</p>	<b>Datenblätter:</b>	 <a href="#">GP1M008A025PG.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 7200 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS

### Spezifikationen

Teilenummer	<a href="#">GP1M008A025PG</a>
Hersteller	<a href="#">Global Power Technologies Group</a>
Beschreibung	MOSFET N-CH 250V 8A IPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	7200 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	52W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	250V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8A (Tc)
Rds On (Max) @ Id, Vgs	600 mOhm @ 4A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8.4nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	423pF @ 25V
Verpackung	Tube















GP1M008A025PG ist neu im Original, Suche GP1M008A025PG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie GP1M008A025PG Global Power Technologies Group mit Garantie und Vertrauen. Anfrage GP1M008A025PG: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>GP1M008A050FG</b> Global Power Technologies Group MOSFET N-CH 500V 8A TO220F</p>	 <p><b>GP1M008A025HG</b> Global Power Technologies Group MOSFET N-CH 250V 8A TO220</p>	 <p><b>GP1M007A090H</b> Global Power Technologies Group MOSFET N-CH 900V 7A TO220</p>	 <p><b>GP1M008A025FG</b> Global Power Technologies Group MOSFET N-CH 250V 8A TO220F</p>
 <p><b>GP1M008A050HG</b> Global Power Technologies Group MOSFET N-CH 500V 8A TO220</p>	 <p><b>GP1M008A050PG</b> Global Power Technologies Group MOSFET N-CH 500V 8A IPAK</p>	 <p><b>GP1M008A025CG</b> Global Power Technologies Group MOSFET N-CH 250V 8A DPAK</p>	 <p><b>GP1M008A050CG</b> Global Power Technologies Group MOSFET N-CH 500V 8A DPAK</p>

### heiße Teile

Mehr

- |   |   |  |  |   |
|---|---|--|--|---|
|  GP1FA502RZ    |  GP1FA513TZ    |  GP1FA51TKOF  |  GP1FA550RZ    |  GP1FA550TZ    |
|  GP1FA551      |  GP1FA551TZ    |  GP1FA553RZ0F |  GP1FA553RZ0F  |  GP1FA553TZ0F  |
|  GP1FAV31TK0F  |  GP1FAV50RK0F  |  GP1FAV50TK0F |  GP1FAV51TK0F  |  GP1FD320TP0F  |
|  GP1FM313TMF5  |  GP1FM313TZMF  |  GP1FSV51TK0F |  GP1L53VJ000F  |  GP1L57J0000F  |
|  GP1M003A050FG |  GP1M003A080CH |  GP1M003A090C |  GP1M006A070FH |  GP1M007A090H  |
|  GP1M009A020FG |  GP1M009A090N  |  GP1M010A060H |  GP1M010A080FH |  GP1M011A050FH |
|  GP1M013A050H  |  GP1M016A025CG |  GP1M016A060F |  GP1M016A060H  |  GP1S092HCPI   |
|  GP1S092HCPIF  |  GP1S092HCPIF  |  GP1S092HCPKF |  GP1S093HCZ    |  GP1S093HCZ0F  |
|  GP1S093HCZ0F  |  GP1S093HCZ0F  |  GP1S094HCZ0F |  GP1S094HCZ0F  |  GP1S094HCZ0F  |
|  GP1S096HCZ    |  GP1S096HCZ0F  |  GP1S096HCZ0F |  GP1S097HCZ0F  |  GP1S194HCZ0F  |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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